

DECLARATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or the below named inventors are the original, first and joint inventors (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled **A METHOD OF FORMING A SUBSTRATE CONTACT IN A FIELD EFFECT TRANSISTOR FORMED OVER A BURIED INSULATOR LAYER**, the Specification of which:

- ☐ is attached hereto.
☒ was filed on **31/10/2000** as Application Serial No. **100 54 109.7** in Germany.

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims.

I acknowledge the duty to disclose to the Patent and Trademark Office all information known to me to be material to patentability of the subject matter claimed in this application, as "materiality" is defined in Title 37, Code of Federal Regulations, § 1.56.

I hereby claim priority benefits under Title 35, United States Code, § 119 and/or § 365 of any foreign application(s) for patent or inventor's certificate, PCT international application(s), and United States provisional application(s), listed below and have also identified below any foreign application for patent or inventor's certificate, PCT international application, or United States provisional application, having a filing date before that of the application on which priority is claimed:

PRIORITY APPLICATION(S)			Priority Claimed
100 54 109.7	Germany	31/10/2000	Yes
(Number)	(Country)	(Date Filed)	Yes/No
(Number)	(Country)	(Date Filed)	Yes/No

I hereby claim the benefit under Title 35, United States Code, § 120 and/or § 365 of any United States application(s) and PCT international application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT international application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose all information known to me to be material to patentability of the subject matter claimed in this application, as "materiality" is defined in Title 37, Code of Federal Regulations, § 1.56, which becomes available between the filing date of the prior application and the national or PCT international filing date of this application:

(Application Serial No.)	(Filing Date)	(Status)
(Application Serial No.)	(Filing Date)	(Status)

I hereby direct that all correspondence and telephone calls be addressed to , Williams, Morgan & Amerson, P.C., 7676 Hillmont, Suite 250, Houston, Texas 77040, (713) 934-7000.

I HEREBY DECLARE THAT ALL STATEMENTS MADE OF MY OWN KNOWLEDGE ARE TRUE AND THAT ALL STATEMENTS MADE ON INFORMATION AND BELIEF ARE BELIEVED TO BE TRUE; AND FURTHER THAT THESE STATEMENTS WERE MADE WITH THE KNOWLEDGE THAT WILLFUL FALSE STATEMENTS AND THE LIKE SO MADE ARE PUNISHABLE BY FINE OR IMPRISONMENT, OR BOTH, UNDER SECTION 1001 OF TITLE 18 OF THE UNITED STATES CODE AND THAT SUCH WILLFUL FALSE STATEMENTS MAY JEOPARDIZE THE VALIDITY OF THE APPLICATION OR ANY PATENT ISSUED THEREON.

Inventor's Full Name:	Gert	Burbach	
Inventor's Signature:	<i>G. Burbach</i>		
Country of Citizenship:	Germany	Date:	31-1-01
Residence Address: (street, number, city, state, and/or country)	Warnemuenderstraße 5A, D-01109 Dresden		
Post Office Address: (if different from above)			

Inventor's Full Name:	Frank	Heinlein	
Inventor's Signature:	<i>Frank Heinlein</i>		
Country of Citizenship:	Germany	Date:	01-Feb-2001
Residence Address: (street, number, city, state, and/or country)	Hubertusstraße 54, D-01129 Dresden		
Post Office Address: (if different from above)			

Inventor's Full Name:	Johannes	Groschopf	
Inventor's Signature:	<i>Johannes Groschopf</i>		
Country of Citizenship:	Germany	Date:	02/10/01
Residence Address: (street, number, city, state, and/or country)	Hauptstraße 27, D-04932 Wainsdorf		
Post Office Address: (if different from above)			

Inventor's Full Name:	Gotthard	Jungnickel	
Inventor's Signature:	<i>G. Jungnickel</i>		
Country of Citizenship:	Germany	Date:	05/02/01
Residence Address: (street, number, city, state, and/or country)	Zur Sternwarte 9, D-01454 Radeberg		
Post Office Address: (if different from above)			

Inventor's Full Name:	Hartmut	Ruelke	
Inventor's Signature:	<i>Hartmut Ruelke</i>		
Country of Citizenship:	Germany	Date:	02 / 05 / 01
Residence Address: (street, number, city, state, and/or country)	Warnemuenderstraße 7, D-01109 Dresden		
Post Office Address: (if different from above)			

Inventor's Full Name:	Carsten	Hartig	
Inventor's Signature:	<i>Carsten Hartig</i>		
Country of Citizenship:	Germany	Date:	02 / 26 / 01
Residence Address: (street, number, city, state, and/or country)	Am Rotenberg 9, D-08393 Meerane		
Post Office Address: (if different from above)			

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Gert Burbach, §
 Frank Heinlein, Johannes §
 Groschopf, Gotthard Jungnickel, § Examiner: Unknown
 Hartmut Ruelke & Carsten Hartig §
 Serial No.: Unknown § Group Art Unit: Unknown
 Filed: Concurrently Herewith § Attorney Docket: 2000.064400/DE0058
 For: Method of Forming a Substrate §
 Contact in a Field Effect §
 Transistor Formed Over a §
 Buried Insulator Layer §

POWER OF ATTORNEY

Assistant Commissioner for Patents

Washington, D.C. 20231

Sir:

The undersigned, being the inventors named in the above-identified application, hereby revoke (revokes) any previous Powers of Attorney and appoint (appoints):

Elizabeth A. Apperley, Reg. No. 36,428; Paul S. Drake, Reg. No. 33,491; Richard J. Roddy, Reg. No. 27,688; Michael Caywood, Reg. No. 37,797; Bradley Botsch, Reg. No. 34,552; Harry A. Wolin, Reg. No. 32,638; and Raj Jaipershad, Reg. No. 44,168; and

Danny L. Williams, Reg. No. 31,892; Terry D. Morgan, Reg. No. 31,181; J. Mike Amerson, Reg. No. 35,426; Kenneth D. Goodman, Reg. No. 30,460; Barbara S. Kitchell, Reg. No. 33,928; Jeffrey A. Pyle, Reg. No. 34,904; Randall C. Furlong, Reg. No. 35,144; Scott F. Diring, Reg. No. 35,119; George J. Oehling, Reg. No. 40,471; Shelley P.M. Fussey, Reg. No. 39,458; Mark D. Moore, Reg. No. 42,903; Louis H. Iselin, Reg. No. 42,684; Raymund F. Eich, Reg. No. 42,508; Bradley A. Misley, Reg. No. 46,937; and Thomas H. Belvin, Jr., Reg. No. 43,491 of Williams, Morgan & Amerson, P.C.,

as its attorney or agent so long as they remain with such firms, with full power of substitution and revocation, to prosecute the application, to make alterations and amendments therein, to transact all business in the Patent and Trademark Office in connection therewith, and to receive any Letters Patent, and for one year after issuance of such Letters Patent to file any request for a certificate of correction that may be deemed appropriate.

Please direct all communications as follows:

J. Mike Amerson
 WILLIAMS, MORGAN & AMERSON, P.C.
 7676 Hillmont, Suite 250
 Houston, Texas 77040
 (713) 934-4055

Signature: _____

Gert Burbach

Date: _____

31-01-01

Signature: _____

Frank Heinlein

Date: _____

01-Feb-2001

Signature: _____

Hartmut Ruelke

Date: _____

02/05/01

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J. Mike Amerson
 WILLIAMS, MORGAN & AMERSON, P.C.
 7676 Hillmont, Suite 250
 Houston, Texas 77040
 (713) 934-40__

Signature: Gottthard JungnickelDate: 02/05/01Signature: Johannes GroschopfDate: 02/10/01Signature: Carsten HartigDate: 02/26/01

Carsten Hartig